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PMEG6002ELDYL

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PMEG6002ELD

60 V, 0.2 A low VF MEGA Schottky barrier rectifier

5 February 2014 Product data sheet

1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a leadless ultra small SOD882D (DFN1006D-2) Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

2. Features and benefits

- Average forward current: $I_{F(AV)} \leq 0.2$ A
- Reverse voltage: $V_R \leq 60$ V
- Low forward voltage $V_F \leq 600$ mV
- AEC-Q101 qualified
- Solderable side pads
- Package height typ. 0.37 mm

3. Applications

- LED backlight for mobile application
- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Low power consumption applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$I_{F(AV)}$	average forward current	δ = 0.5; f = 20 kHz; $T_{amb} \leq 130$ °C; square wave	[1]	-	-	0.2	A
		δ = 0.5; f = 20 kHz; $T_{sp} \leq 140$ °C; square wave		-	-	0.2	A
V_R	reverse voltage	T_j = 25 °C		-	-	60	V
V_F	forward voltage	I_F = 200 mA; pulsed; $t_p \leq 300$ µs; δ ≤ 0.02; T_j = 25 °C		-	540	600	mV
I_R	reverse current	V_R = 10 V; pulsed; $t_p \leq 2$ ms; δ ≤ 0.02; T_j = 25 °C		-	2	10	µA

[1] Device mounted on a ceramic PCB, Al_2O_3, standard footprint.

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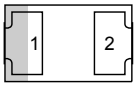
5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]	 Transparent top view **DFN1006D-2 (SOD882D)**	
2	A	anode		

[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMEG6002ELD	DFN1006D-2	DFN1006D-2: leadless ultra small plastic package; 2 terminals	SOD882D

7. Marking

Table 4. Marking codes

Type number	Marking code
PMEG6002ELD	1111 1010

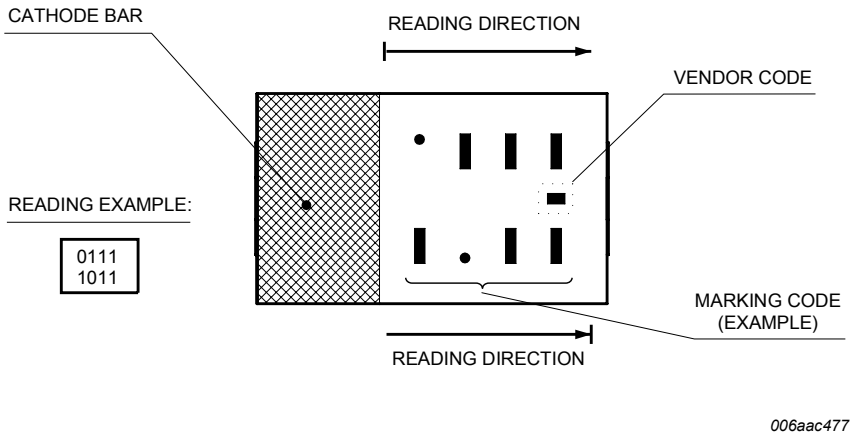


Fig. 1. SOD882D binary marking code description

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_R	reverse voltage	T_j = 25 °C		-	60	V
I_F	forward current	T_{sp} ≤ 140 °C		-	0.28	A
$I_{F(AV)}$	average forward current	δ = 0.5; f = 20 kHz; T_{amb} ≤ 130 °C; square wave	[1]	-	0.2	A
		δ = 0.5; f = 20 kHz; T_{sp} ≤ 140 °C; square wave		-	0.2	A
I_{FRM}	repetitive peak forward current	t_p ≤ 1 ms; δ ≤ 0.25		-	1	A
I_{FSM}	non-repetitive peak forward current	t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	3	A
P_{tot}	total power dissipation	T_{amb} ≤ 25 °C	[2]	-	370	mW
			[3]	-	735	mW
			[1]	-	1090	mW
T_j	junction temperature			-	150	°C
T_{amb}	ambient temperature			-55	150	°C
T_{stg}	storage temperature			-65	150	°C

[1] Device mounted on a ceramic PCB, Al_2O_3, standard footprint.
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm^2.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	-	340	K/W
			[1][3]	-	-	170	K/W
			[1][4]	-	-	115	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[5]	-	-	20	K/W

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm^2.
[4] Device mounted on a ceramic PCB, Al_2O_3, standard footprint.
[5] Soldering point of cathode tab.

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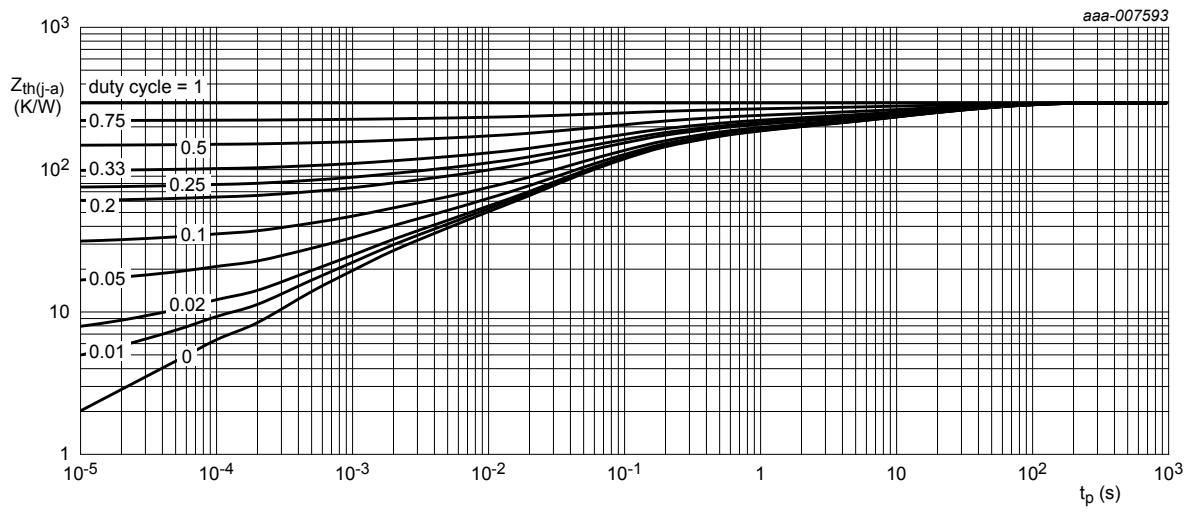
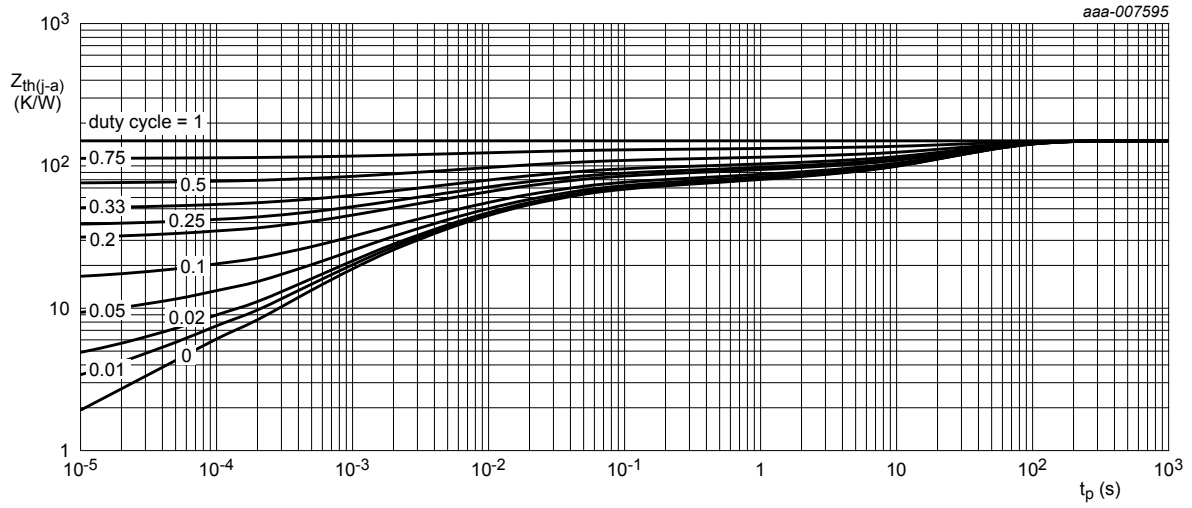


FR4 PCB, standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for cathode 1 cm^2

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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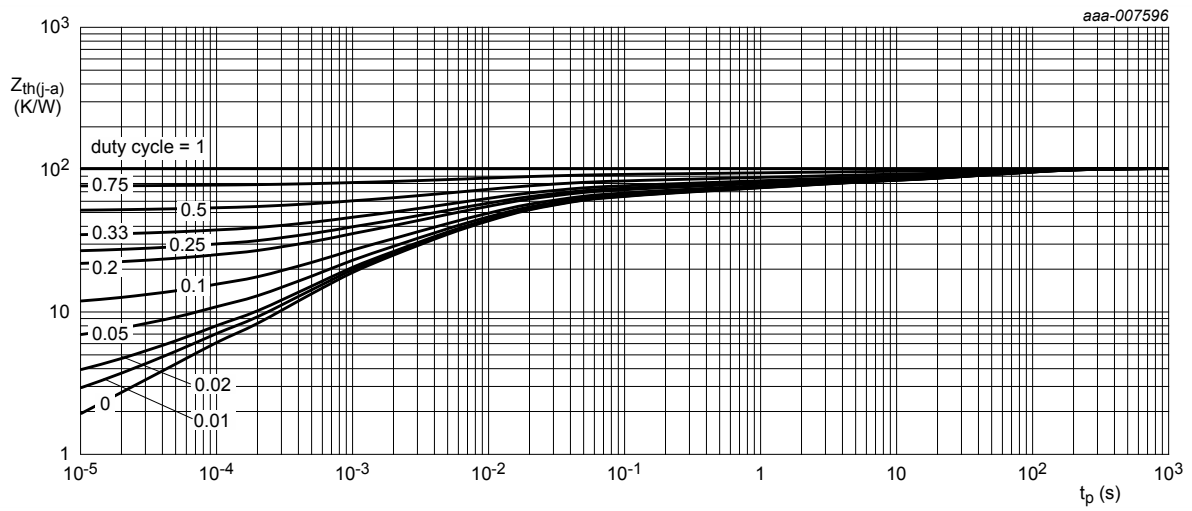

Ceramic PCB, Al_2O_3, standard footprint

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_F	forward voltage	I_F = 0.1 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C		-	130	170	mV
		I_F = 1 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C		-	190	230	mV
		I_F = 10 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C		-	260	300	mV
		I_F = 100 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C		-	410	470	mV
		I_F = 200 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C		-	540	600	mV
I_R	reverse current	V_R = 10 V; pulsed; t_p ≤ 2 ms; δ ≤ 0.02; T_j = 25 °C		-	2	10	μA
		V_R = 60 V; pulsed; t_p ≤ 2 ms; δ ≤ 0.02; T_j = 25 °C		-	20	100	μA
		V_R = 10 V; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 100 °C		-	310	-	μA
		V_R = 60 V; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 100 °C		-	2	-	mA
C_d	diode capacitance	V_R = 1 V; f = 1 MHz; T_j = 25 °C		-	15	20	pF
t_{rr}	reverse recovery time	I_F = 10 mA; I_R = 10 mA; R_L = 100 Ω; $I_{R(meas)}$ = 1 mA; T_j = 25 °C		-	4.5	-	ns

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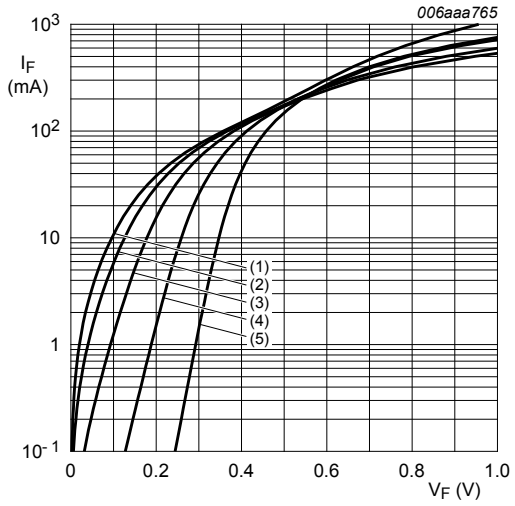
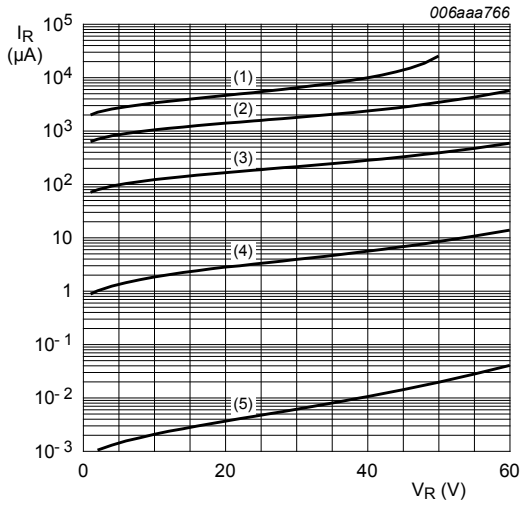


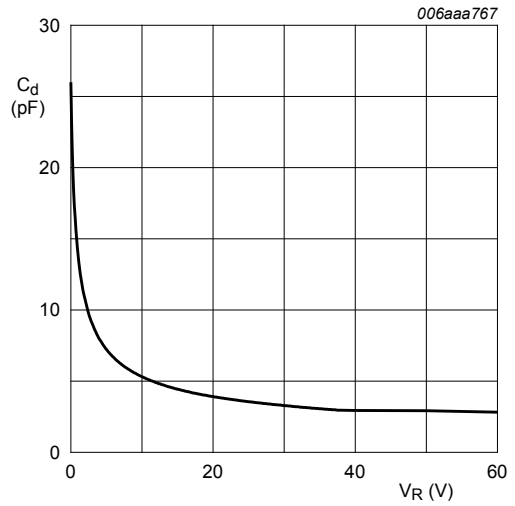
(1) T_j = 150 °C
(2) T_j = 125 °C
(3) T_j = 85 °C
(4) T_j = 25 °C
(5) T_j = −40 °C

Fig. 5. Forward current as a function of forward voltage; typical values



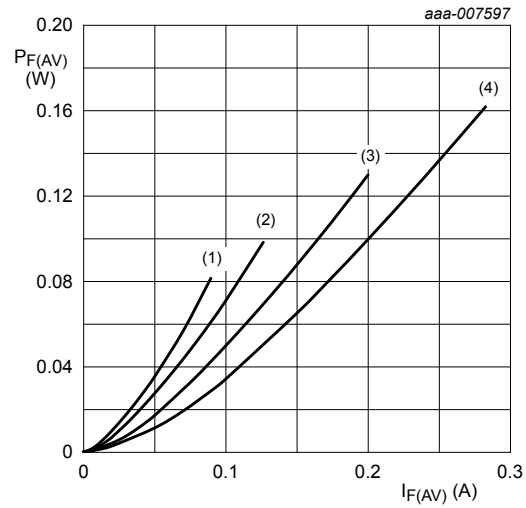
(1) T_j = 150 °C
(2) T_j = 125 °C
(3) T_j = 85 °C
(4) T_j = 25 °C
(5) T_j = −40 °C

Fig. 6. Reverse current as a function of reverse voltage; typical values



f = 1 MHz; T_{amb} = 25 °C

Fig. 7. Diode capacitance as a function of reverse voltage; typical values



T_j = 150 °C
(1) δ = 0.1; f = 20 kHz
(2) δ = 0.2; f = 20 kHz
(3) δ = 0.5; f = 20 kHz
(4) δ = 1 (DC)

Fig. 8. Average forward power dissipation as a function of average forward current; typical values

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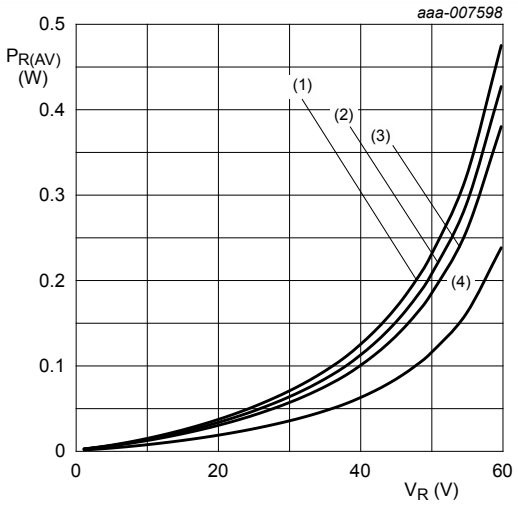
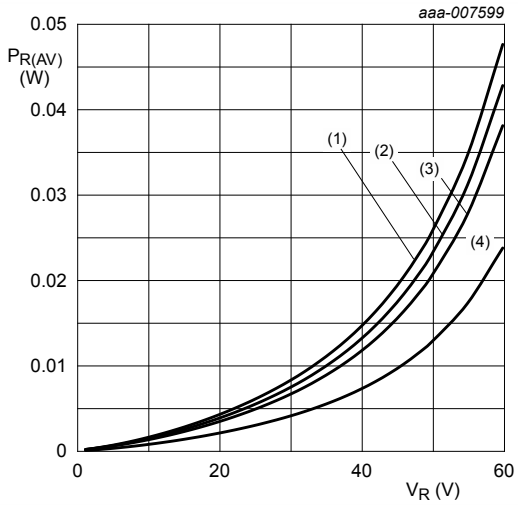


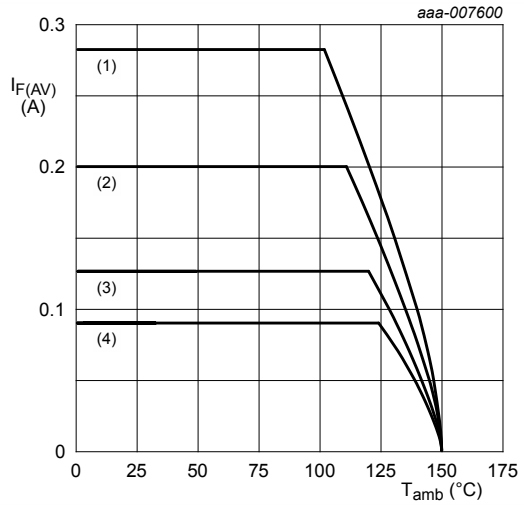
T_j = 125 °C
(1) δ = 1 (DC)
(2) δ = 0.9; f = 20 kHz
(3) δ = 0.8; f = 20 kHz
(4) δ = 0.5; f = 20 kHz

Fig. 9. Average reverse power dissipation as a function of reverse voltage; typical values



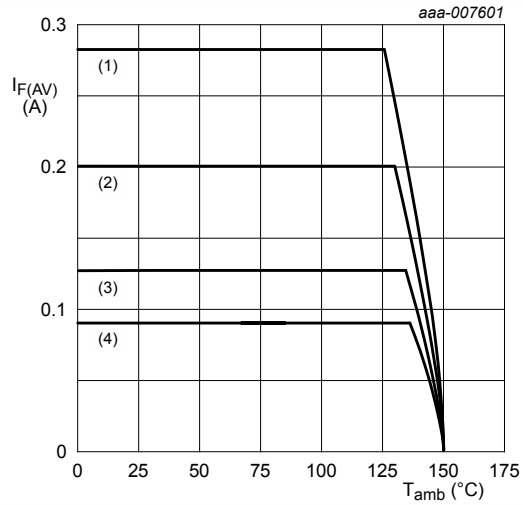
T_j = 85 °C
(1) δ = 1 (DC)
(2) δ = 0.9; f = 20 kHz
(3) δ = 0.8; f = 20 kHz
(4) δ = 0.5; f = 20 kHz

Fig. 10. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint
T_j = 150 °C
(1) δ = 1 (DC)
(2) δ = 0.5; f = 20 kHz
(3) δ = 0.2; f = 20 kHz
(4) δ = 0.1; f = 20 kHz

Fig. 11. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm^2
T_j = 150 °C
(1) δ = 1 (DC)
(2) δ = 0.5; f = 20 kHz
(3) δ = 0.2; f = 20 kHz
(4) δ = 0.1; f = 20 kHz

Fig. 12. Average forward current as a function of ambient temperature; typical values

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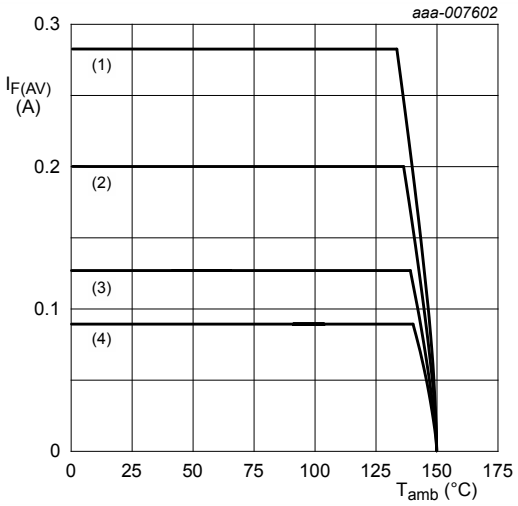


Ceramic PCB, Al_2O_3, standard footprint

T_j = 150 °C

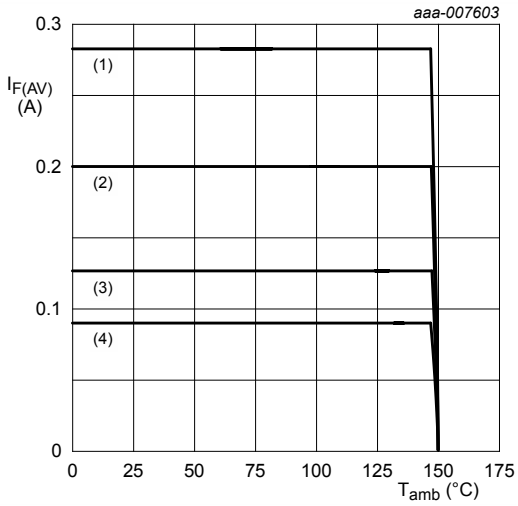
(1) δ = 1 (DC)

(2) δ = 0.5; f = 20 kHz

(3) δ = 0.2; f = 20 kHz

(4) δ = 0.1; f = 20 kHz

Fig. 13. Average forward current as a function of ambient temperature; typical values



T_j = 150 °C

(1) δ = 1 (DC)

(2) δ = 0.5; f = 20 kHz

(3) δ = 0.2; f = 20 kHz

(4) δ = 0.1; f = 20 kHz

Fig. 14. Average forward current as a function of solder point temperature; typical values

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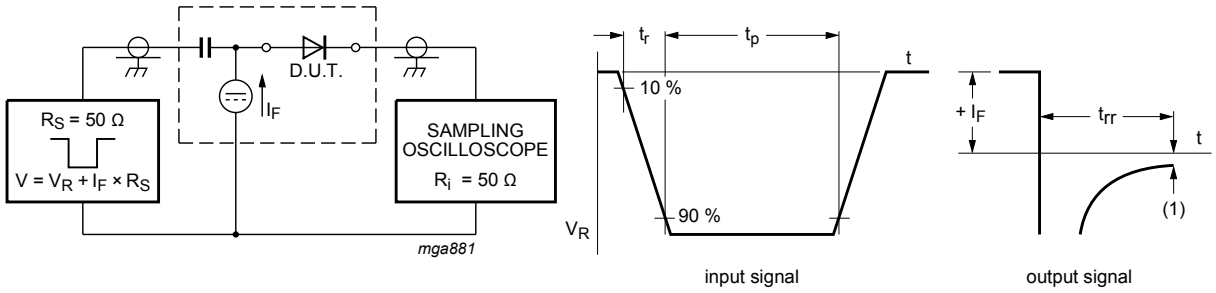
11. Test information



(1) I_R = 1 mA

Fig. 15. Reverse recovery time: test circuit and waveforms

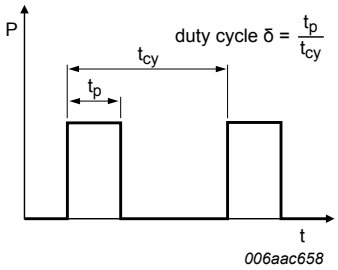


Fig. 16. Duty cycle definition

The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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12. Package outline

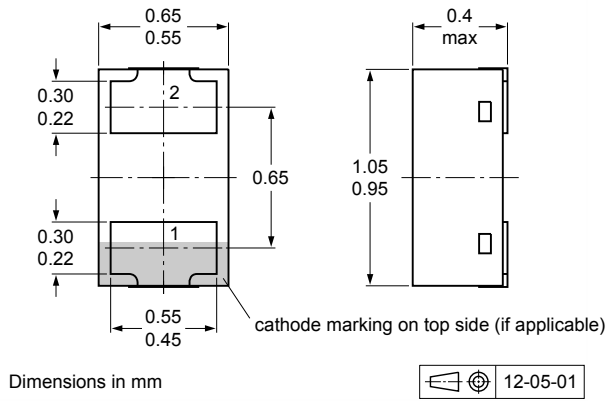

Fig. 17. Package outline DFN1006D-2 (SOD882D)

13. Soldering

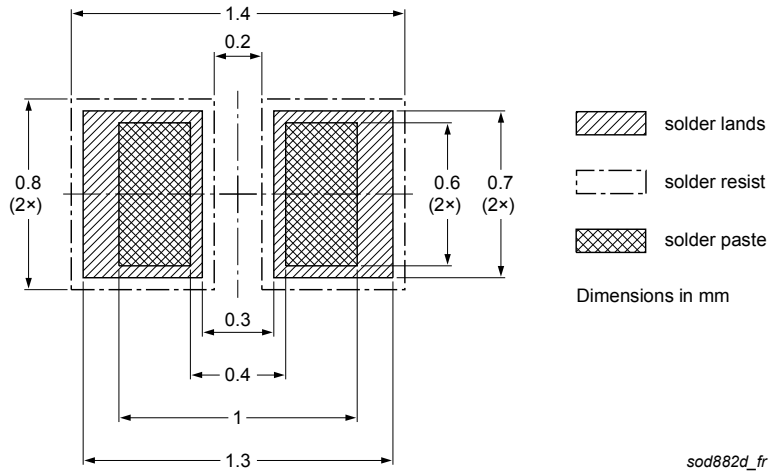

Fig. 18. Reflow soldering footprint for DFN1006D-2 (SOD882D)

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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMEG6002ELD v.3	20140205	Product data sheet	-	PMEG6002ELD v.2
Modifications:	• Table 7. Characteristics: I_R conditions corrected			
PMEG6002ELD v.2	20131210	Product data sheet	-	PMEG6002ELD v.1
PMEG6002ELD v.1	20130503	Product data sheet	-	-

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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